

FMV20N60S1

FUJI POWER MOSFET

Super J-MOS series

N-Channel enhancement mode power MOSFET

■ Features

Low on-state resistance Low switching loss easy to use (more controllabe switching dV/dt by Rg)

Applications

UPS

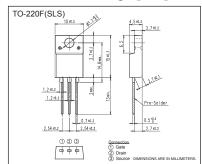
Server

Telecom

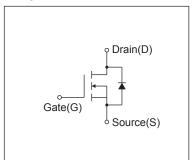
Power conditioner system

Power supply

■ Outline Drawings [mm]



■ Equivalent circuit schematic



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings at T_c=25°C (unless otherwise specified)

Description	Symbol	Characteristics	Unit	Remarks	
Dunius Common Voltano	V _{DS}	600	V		
Drain-Source Voltage	V _{DSX}	600	V	V _{GS} =-30V	
Continuous Drain Current	l _D	±20	Α	Tc=25°C Note*1	
		±12.6	Α	Tc=100°C Note*1	
Pulsed Drain Current	IDP	±60	Α		
Gate-Source Voltage	V _{GS}	±30	V		
Repetitive and Non-Repetitive Maximum Avalanche Current	lar	6.6	А	Note *2	
Non-Repetitive Maximum Avalanche Energy	Eas	472.2	mJ	Note *3	
Maximum Drain-Source dV/dt	dV _{DS} /dt	50	kV/μs	V _{DS} ≤ 600V	
Peak Diode Recovery dV/dt	dV/dt	15	kV/μs	Note *4	
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note *5	
Maximum Power Dissipation	P₀	2.16	14/	Ta=25°C	
		53	W	Tc=25°C	
On another and Otenses Terranecture	Tch	150	°C		
Operating and Storage Temperature range	Tstg	-55 to +150 °C			
Isolation Voltage	V _{iso}	2	kVrms	t=60sec,f=60Hz	

Note *1 : Limited by maximum channel temperature. Note *2 : Tch≤150°C, See Fig.1 and Fig.2 Note *3 : Starting Tch=25°C, Ias=2A, L=216mH, Vbb=60V, Rc=50Ω, See Fig.1 and Fig.2

EAS limited by maximum channel temperature and avalanche current.

Note *4 : Ir≤-Ip, -di/dt=100A/µs, Vpp≤400V, Tch≤150°C.

Note *5 : Ir≤-Ip, dV/dt=15kV/µs, Vpp≤400V, Tch≤150°C.

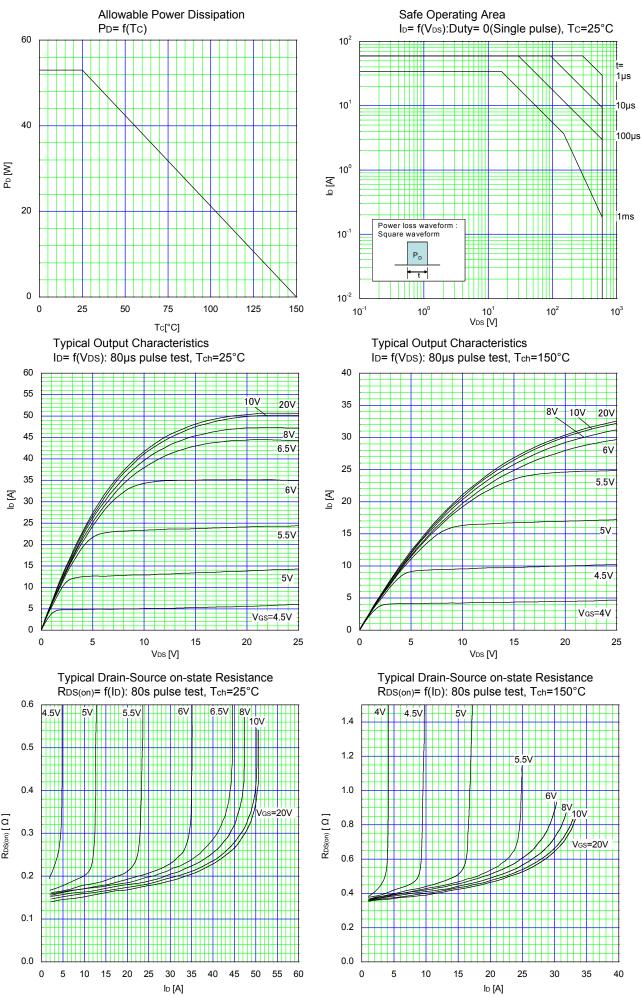
● Electrical Characteristics at T₀=25°C (unless otherwise specified) Static Ratings

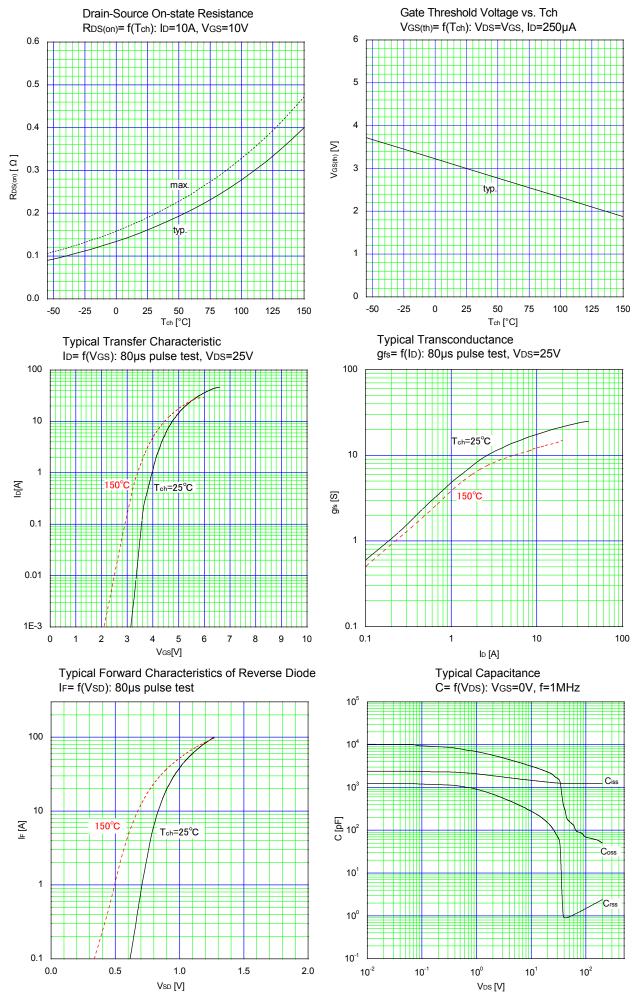
Description	Symbol	Conditions		min.	typ.	max.	Unit	
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250μA V _{GS} =0V		600	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	I _D =250μA V _{DS} =V _{GS}		2.5	3	3.5	V	
Zero Gate Voltage Drain Current		V _{DS} =600V V _{GS} =0V	T _{ch} =25°C	-	-	25	μА	
	loss	V _{DS} =480V V _{GS} =0V	T _{ch} =125°C	-	-	250		
Gate-Source Leakage Current	Igss	V _{GS} = ± 30V V _{DS} =0V		-	10	100	nA	
Drain-Source On-State Resistance	R _{DS(on)}	I _D =10A V _{GS} =10V		-	0.161	0.19	Ω	
Gate resistance	Rg	f=1MHz, open drain		-	3.7	-	Ω	
Forward Transconductance	g _{fs}	I _D =10A VDS=25V		8.5	17.5	-	S	
Input Capacitance	Ciss	V _{DS} =10V V _{GS} =0V		-	1470	-		
Output Capacitance	Coss			-	3120	-		
Reverse Transfer Capacitance	Crss	f=1MHz		-	280	-	1	
Effective output capacitance, energy related (Note *6)	C _{o(er)}	V _{GS} =0V V _{DS} =0480V		-	90	-	pF	
Effective output capacitance, time related (Note *7)	C _{o(tr)}	V _{GS} =0V V _{DS} =0480V ID=constant		-	305	-		
Turn-On Time tr	t _{d(on)}			-	22	-		
	tr	V _{DD} =400V, V _{GS} =10V I _D =10A, R _G =27Ω See Fig.3 and Fig.4		-	40	-	ns	
Turn-Off Time	t _{d(off)}			-	162	-		
	tr			-	22	-		
Total Gate Charge	Q _G	V _{DD} =480V, I _D =20A		-	48	-	nC	
Gate-Source Charge	Q _{GS}			-	12.5	-		
Gate-Drain Charge	Q _{GD}	See Fig.5	V _{GS} =10V		15	-		
Drain-Source crossover Charge	Qsw	- See Fig.5		-	8	-		
Avalanche Capability	lav	L=6.02mH,Tch=25°C See Fig.1 and Fig.2		6.6	-	-	А	
Diode Forward On-Voltage	V _{SD}	I _F =20A,V _{GS} =0V T _{ch} =25°C		-	0.9	1.35	V	
Reverse Recovery Time	trr	I _F =20A, V _{GS} =0V			370	-	ns	
Reverse Recovery Charge	Qır	V _{DD} =400V -di/dt=100A/μsT _{ch} =25°C See Fig.6		-	6.2	-	μC	
Peak Reverse Recovery Current	Irp			-	32	-	А	

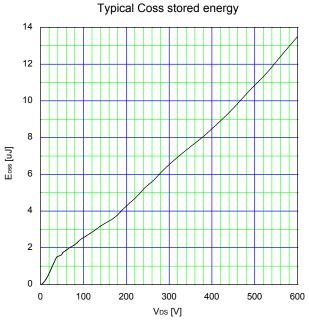
Note *6: $C_{o(er)}$ is a fixed capacitance that gives the same stored energy as C_{oss} while V_{DS} is rising from 0 to 80% BVDss. Note *7: $C_{o(tr)}$ is a fixed capacitance that gives the same charging times as C_{oss} while V_{DS} is rising from 0 to 80% BVDss.

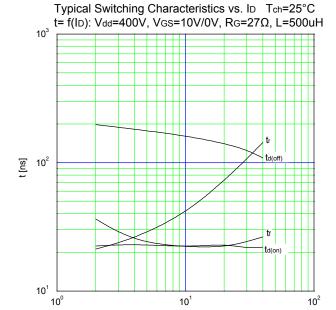
Thermal Characteristics

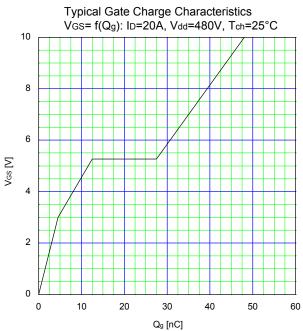
Description	Symbol	min.	typ.	max.	Unit
Channel to Case	Rth(ch-c)			2.36	°C/W
Channel to Ambient	Rth(ch-a)			58	°C/W

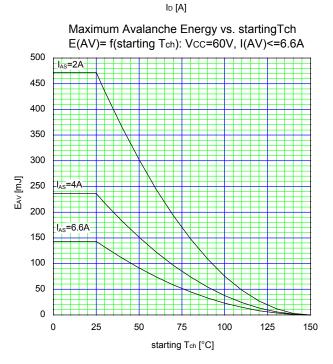


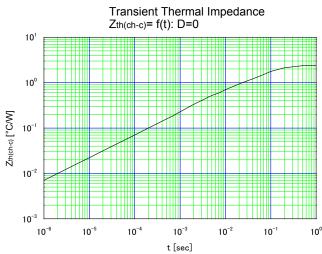




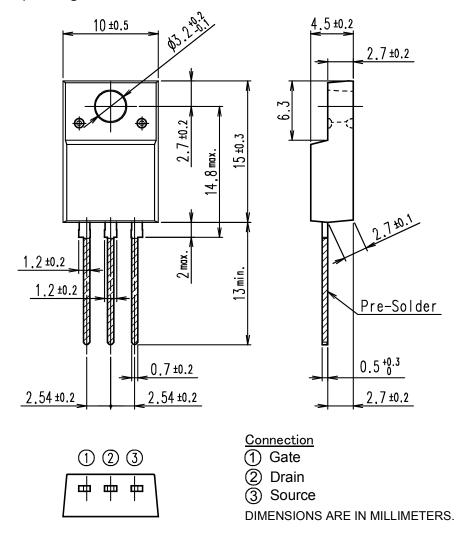




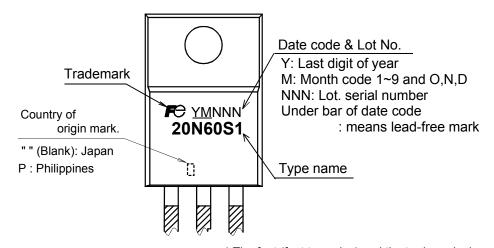




■ Outview: TO-220F(SLS) Package



■ Marking



^{*} The font (font type,size) and the trademark-size might be actually different.

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- · Machine tools
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- Personal equipment Industrial robots etc.

Trunk communications equipment

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